

PS-C5

Effect of Interlayer Spin-flip Tunneling for Interlayer Magnetoresistance in Multilayer Dirac Fermion Systems

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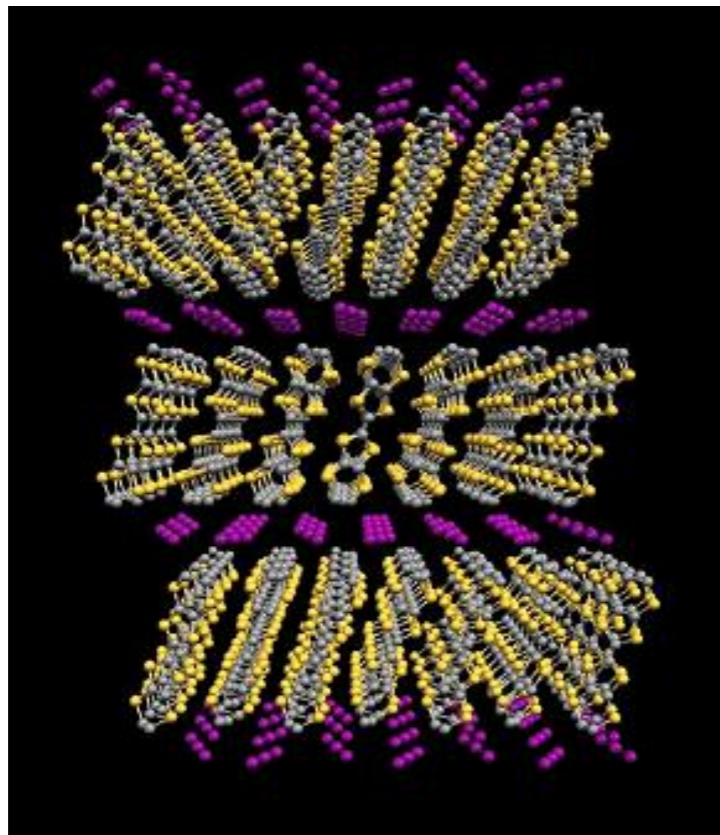
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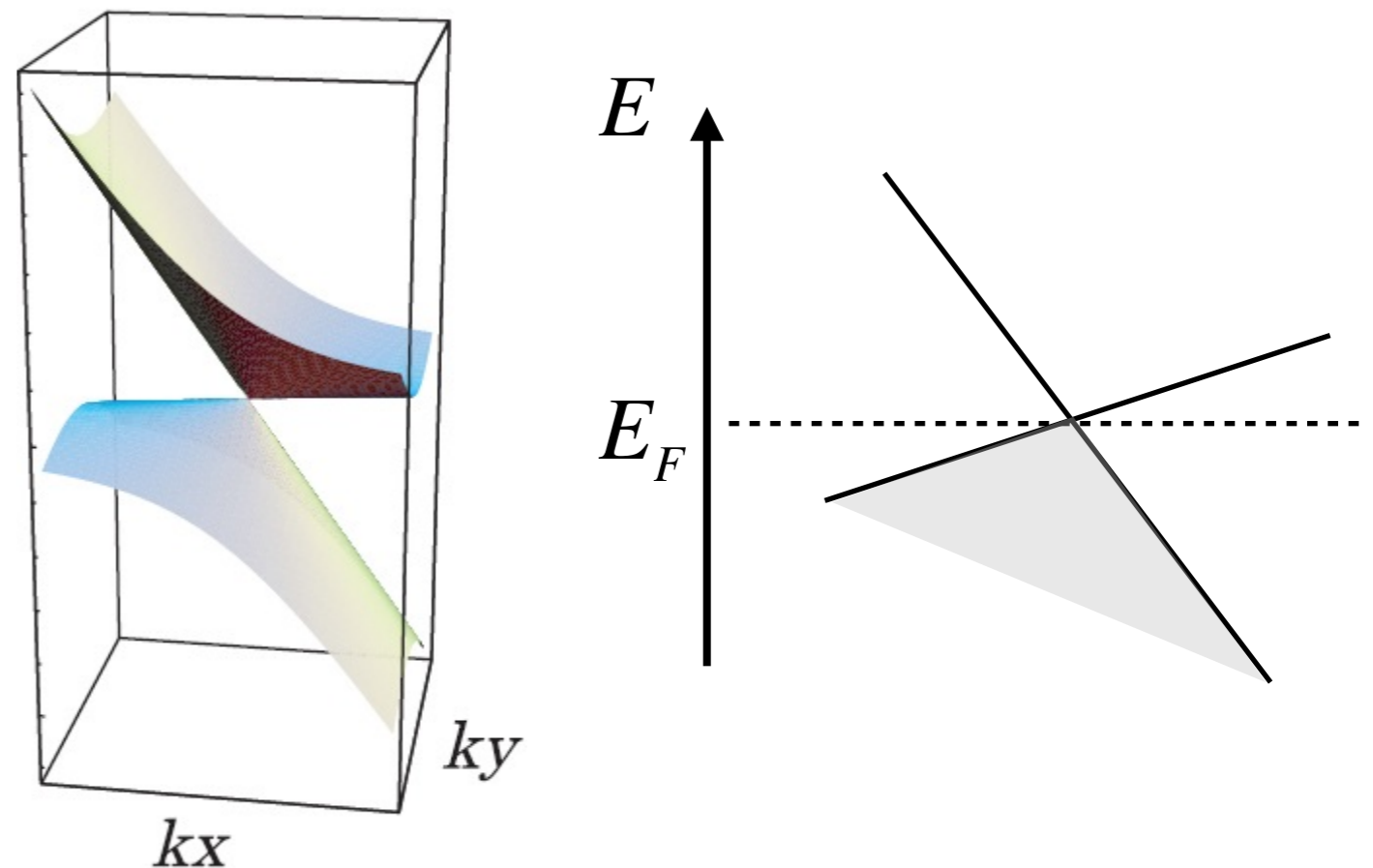
K. Kubo, T. Morinari, J. Phys. Soc. Jpn. **83**, 083701 (2014)

α -(BEDT-TTF)₂I₃

- **Dirac fermion system** under high pressure Tajima et al., 2000, 2006
- **Multilayered system** with conducting layers of BEDT-TTF molecules and insulating layers of I₃ anions.



N. Tajima, (RIKEN)

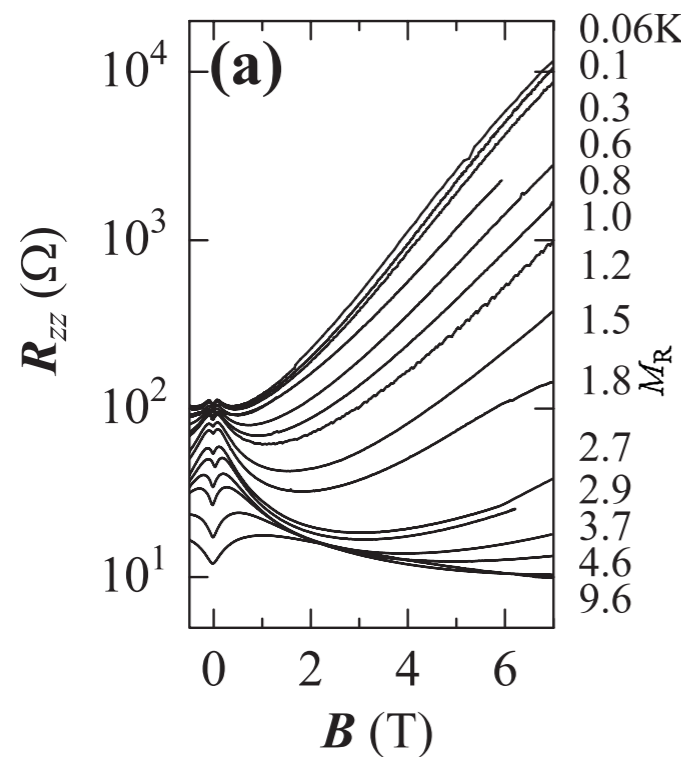


A. Kobayashi et al., (2004)

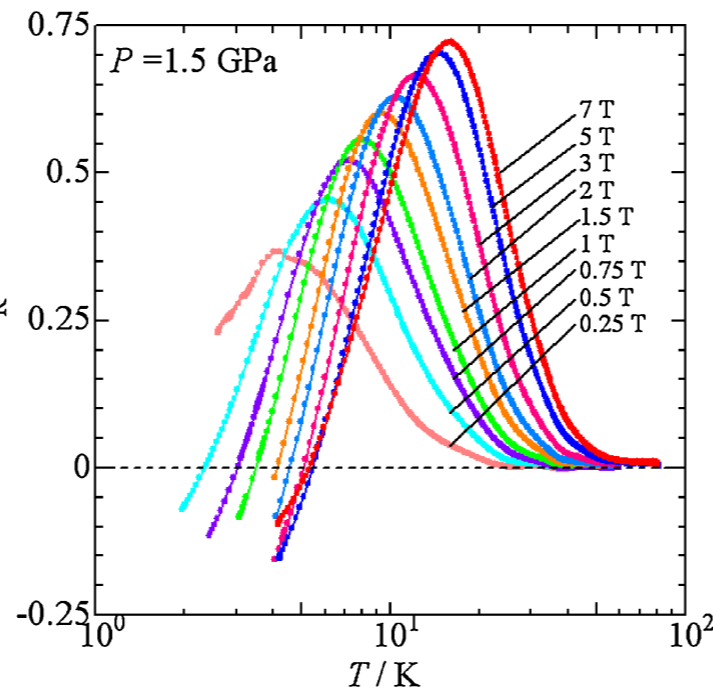
S. Katayama, A. Kobayashi, Y. Suzumura, (2006)

Motivation

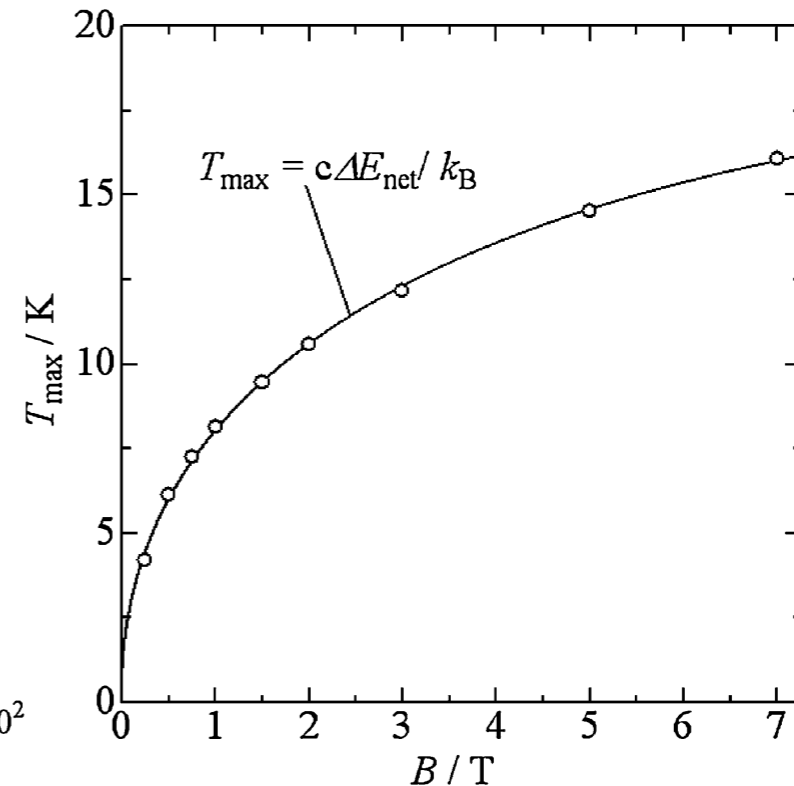
- α -(BEDT-TTF)₂I₃ has unique interlayer magnetoresistance



N. Tajima et al., (2009)



S. Sugawara et al, (2010)

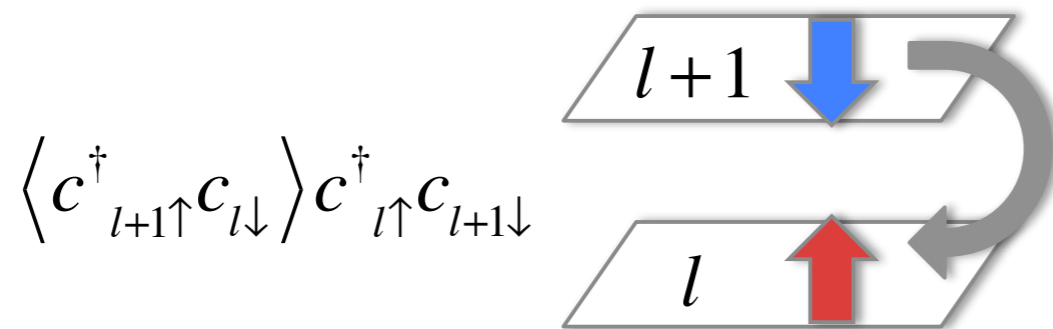


- Previous theoretical research : $T_{\max} = C\sqrt{B}$ T. Morinari and T. Tohyama, (2010)
- Experimental result : $T_{\max} = C\sqrt{B} - g\mu_B B$
 → Peak temperature is shifted by the Zeeman energy.
- The interlayer tunneling should be related to spin-flip processes.

Results

- The opposite spin mean field arise from the interlayer Coulomb interaction

- The opposite spin mean field leads the interlayer spin-flip tunneling



- The peak temperature of the interlayer magnetoresistance is shifted by the Zeeman energy.

